# NSN 5961-01-196-6939

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# **Inclosure Material:**

Plastic

**Overall Length:** 

0.360 inches

# **Overall Height:**

0.183 inches

# **Overall Width:**

0.410 inches

# **Mounting Facility Quantity:**

1

# Internal Configuration:

Junction contact-darlington connected

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-202

# **Mounting Method:**

# Unthreaded hole

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, collector-to-base, emitter open and 12.0 emitter to base voltage, static, collector open and 40.0 breakdown

voltage, collector-to-emitter, base open

# **Current Rating Per Characteristic:**

2.00 amperes source cutoff current and 100.00 milliamperes source cutoff current

# **Power Rating Per Characteristic:**

2.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# Terminal Type And Quantity:

3 pin

# Specification Data:

80131-release6599a professional/industrial association specification

# Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

# Fiig:

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